

## **Preliminary Datasheet**

## N-Channel 30-V (D-S) MOSFET

#### **FEATURES**

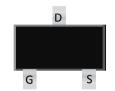
- Advance Trench Process Technology
- High Density Cell Design for Ultra Low On-resistance

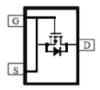
PRODUCTY SUMMARY				
$V_{DS}$	R	$_{DS(on)} m(\Omega)$	I <sub>D</sub> (A)	
30	30	Rdson @10V	4.2	
30	50	Rdson @4.5V	3.3	

## **Application**

- ●Portable Devices
- ■Consumer Electronics

# SOT-23





#### Mechanical

●Case: SOT-23 Package

#### **Packing Information**

Package	Packing	
SOT-23	3Kpcs / 7" Reel	

Maximum Ratings (T <sub>A</sub> =25°C unless otherwise specified)						
Parameter		Limit	Unit			
Drain-Source Voltage	$V_{DS}$	30	V			
Gate-Source Voltage	$V_{GS}$	±20	V			
Continuous Drain Current 1)	I <sub>D</sub>	4.2	А			
Maximum Power Dissipation	$P_D$	1.6	W			
Pulsed Drain Current 2)	I <sub>DM</sub>	16.8	А			
Operating Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to 150	°C			

Typical Thermal Resistance					
Parameter		Limit	Unit		
Junction-to-Ambient Thermal Resistance		100	°C/W		

#### Note:

RθJA is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper



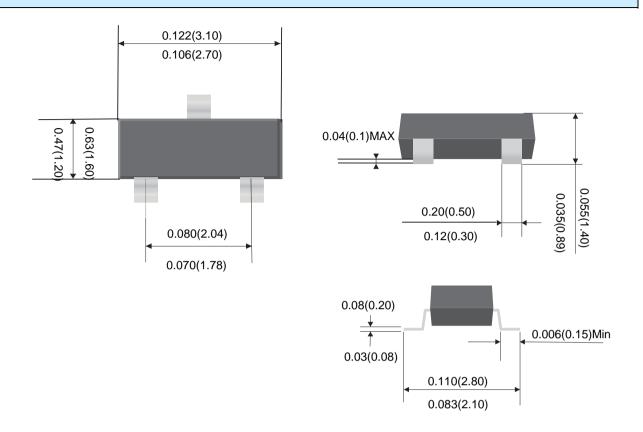
Electrical Characteristics (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)						
Characteristics	Symbol	Test Condition	Limits			11
Characteristics			Min	Тур	Max	Unit
Static						
Drain-Source Breakdown Voltage	B <sub>VDSS</sub>	VGS = 0V, I <sub>D</sub> =250uA	30			V
Gate Threshold Voltage	$V_{GS(th)}$	VDS=VGS, I <sub>D</sub> =250uA	1	-	2.5	V
Drain-Source On-State Resistance	Б	V <sub>GS</sub> =10.0V, I <sub>D</sub> =4.2A	-	21	30	mΩ
Dialii-Source Oil-State Resistance	$R_{DS(on)}$	VGS=4.5V, ID=3.3A	-	35	50	mΩ
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	VDS=30V, VGS=0V	-	-	-1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V	-	-	±100	nA
		Dynamic 3)				
Total Gate Charge	$Q_g$	$V_{DS}$ =-15V, $I_{D}$ =4.5A, $V_{GS}$ =10V (Note 1,2)	-	8.4	-	nC
Gate-Source Charge	$Q_{gs}$	VDS=-15V, ID=4.5A, VGS=4.5V (Note 1,2)	-	4.7	-	nC
Gate-Drain Charge	$Q_{gd}$	VDS=-15V, ID=4.5A, VGS=4.5V (Note 1,2)	-	1.7	-	nC
Input Capacitance	C <sub>iss</sub>		-	330	-	pF
Output Capacitance	C <sub>oss</sub>	$V_{DS}$ =15V, $V_{GS}$ =0V, f=1.0MHZ	-	55	-	pF
Reverse Transfer Capacitance	C <sub>rss</sub>	1-1.01/11/12	-	45	-	pF
		Switching				
Turn-On Delay Time	$t_{d(on)}$		-	6	-	ns
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =15V, $I_{D}$ =2.25A, $V_{GS}$ =-10V,RG=10 $\Omega$ (Note 1,2)	_	11	_	ns
Turn-Off Delay Time	t <sub>d(off)</sub>		-	12	-	ns
Turn-Off Fall Time	t <sub>f</sub>		-	6	-	ns
Drain-Source Diode						
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =-0.8A, V <sub>GS</sub> =0V	-	-	1.2	V

## Note:

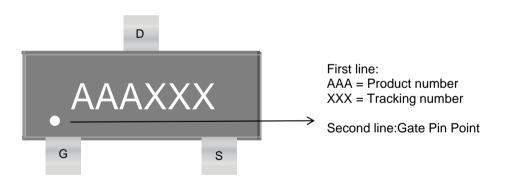
- 1. Pulse width<300us, Duty cycle<2%
- 2. Fused current that based on wire numbers and diameter
- 3. Guaranteed by design, not subject to production testing.



### Package Outline Dimensions (inches and millimeters)



#### **Marking Information**



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